

GPON OLT BOSA

BA-34 series T2.5G/R1.25G

Features

- Receptacle type single fiber bi-directional transmission designed for Passive Optical Network (PON) digital communication
- Asymmetric 2.5Gbps downstream and 1.25Gbps upstream data link transmission
- Laser welded transmitter and epoxy cured receiver package
- Integrated micro-optics WDM filters for dual wavelength Tx/Rx operation at 1310/1490nm
- 1490nm InGaAsP/InP MQW DFB laser diode transmission with high bandwidth InGaAs monitor photodiode
- 1310nm digital APD with integrated 1.25Gbps, 3.3V burst mode transimpedance-amplifier
- Built-in free-space optical isolation, high optical isolation from external source and low optical cross-talk from internal source
- -5°C to 85°C extended commercial operating temperature range with excellent temperature dependent power tracking error

Description

This GPON OLT BOSA is a high performance optical sub-assembly in single fiber by using 1490nm transmitter and 1310nm burst mode receiver with 1550/1650nm optical signal rejection.

The transmitter section uses a multiple quantum well 1490nm DFB laser and is class I laser complaint product according to International Safety Standard IEC-60825. Supporting burst-mode operation, the receiver section uses a TO-can built in a 1310nm APD chip and a burst mode trans-impedance amplifier.

Applications

- GPON Bi-directional play transceiver, OLT
- FTTH Bi-directional play

Standard

- Compliant with ITU-T G984.5 telecommunication protocol
- Compliant with Telcordia GR-468 reliability test criterion
- Compliant with RoHS6 standard

1. Absolute Maximum Ratings

Item	Unit	Min	Max	Note
Forward Current for LD	mA	—	150	
Reverse Voltage for LD	V	—	2	
Forward Current for MPD	mA	—	2	
Reverse Voltage for MPD	V	—	20	
APD Reverse Voltage	V		Vbr	
TIA Supply Voltage	V	—	3.6	
Operating Temperature	°C	-5	85	
Storage Temperature	°C	-40	85	
Storage Relative Humidity	%	—	95	
Solder Reflow Temperature	°C	—	370 (Max.10sec)	
ESD threshold	V	—	500	

2. Transmitter Electro-Optical Characteristics ($T_c=25^{\circ}\text{C}$, CW)

Item	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Threshold Current	I_{th}	$T_c=25^{\circ}\text{C}$	—	8	15	mA
		$T_c=85^{\circ}\text{C}$	—	—	35	mA
Optical Output Power (*2)	P_f	$I_f=I_{\text{th}}+20\text{mA}$, $T_c=25^{\circ}\text{C}$	2.3	2.8	6.0	mW
Forward Voltage	V_f	$I_f=I_{\text{th}}+20\text{mA}$	—	1.1	1.5	V
Peak Wavelength	λ	$I_f=I_{\text{th}}+20\text{mA}$	1480	1490	1500	nm
Spectrum Width (-20dB)	$\Delta\lambda$	$I_f=I_{\text{th}}+20\text{mA}$	—	—	1.0	nm
Side Mode Suppression Ratio	SMSR	$I_f=I_{\text{th}}+20\text{mA}$	30	—	—	dB
Monitor Current	I_m	$P_f=2.3\text{mW}$	0.08	—	1	mA
Monitor Dark Current	I_d	$V_{rp}=10\text{V}$	—	—	100	nA
Rise/fall Time	τ_r/τ_f	20%~80%	—	0.1	0.2	ns
Tracking Error (*3)	TE	$T_c = -5 \sim 85^{\circ}\text{C}$	-1.5	—	1.5	dB

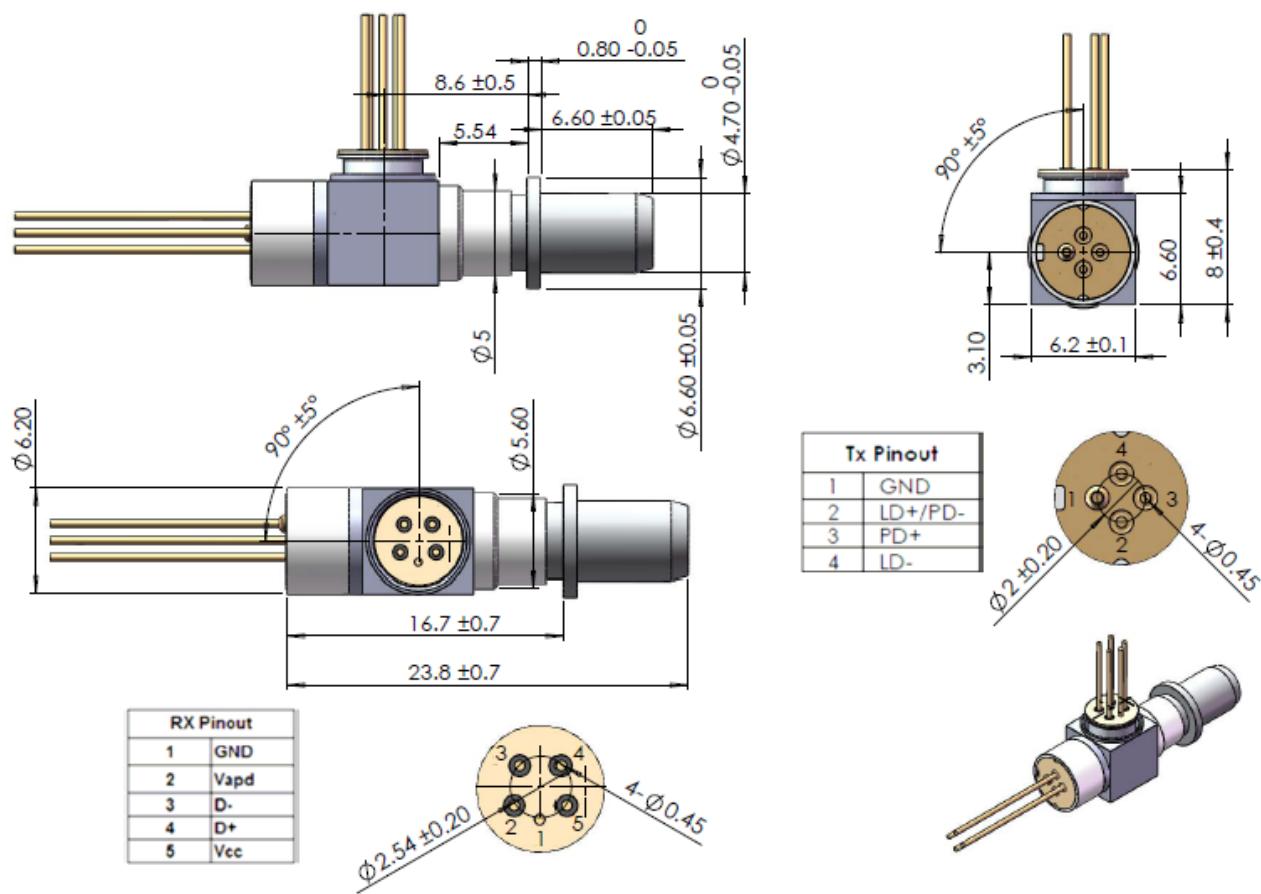
(*2): Launched into 9/125 μm SMF

(*3): $\Delta P_f = 10 \times \log(P_f(T_c)/P_f(25^{\circ}\text{C}))$, I_m hold(@ $P_f=2.5\text{mW}$, 25°C)

3. Digital Receiver Electro-Optical Characteristics (TC=25°C, Vcc=3.3V)

Item	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Supply Voltage	Vcc	No load	3.1	3.3	3.6	V
Supply Current	Icc	Vcc	-	46	55	mA
Dark Current	Id	Vapd=0.9*Vbr, 25°C	10	-	150	nA
Operating Wavelength	λc	-	1260	-	1360	nm
Breakdown Voltage	Vbr	25°C, TIA off	37	-	50	V
Sensitivity	Sen	PRBS23, 1.25Gbps, ER=10dB, BER=10E-10	-	-	-33	dBm
Overload	OL		-6	-	-	dBm
Responsivity	Res	@Vpd=3.3V	0.75	-	-	A/W
Optical Return Loss	ORL1310	@1310nm	-	-	-10	dB
	ORL1490	@1490nm	-	-	-10	dB
	ORL1550	@1550nm	-	-	-10	dB
Optical Crosstalk	X-talk	1310nm/1490nm	-	-	-45	dB
Optical Isolation	ISO	λ=1260~1360nm	-	-	-40	dB
		λ=1550~1560nm	-	-	-40	dB
		λ=1640~1660nm	-	-	-40	dB

4. Dimension Outline (Unit: mm)



5. Other Characteristics ($T_c=25^\circ\text{C}$)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Note
Fiber Mode Field Diameter		8	9	10	μm	
Pull Force on LD Assembly		30	--	--	Kgw	
Pull Force on APD Assembly		15	--	--	Kgw	
Shear Strength on XY Welding		30	--	--	Kgw	
Connector Repeatability (*4)		-1.0	-	+1.0	dB	

(*4): Same plug orientation, same patchcord, 5 times, Launched into 9/125 μm SMF, measured with a master plug and an extra receptacle